

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

2SC3279

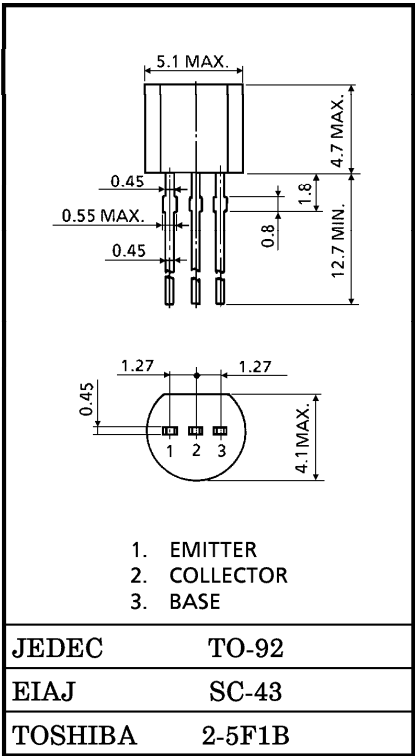
Unit in mm

STOROBO FLASH APPLICATIONS
MEDIUM POWER AMPLIFIER APPLICATIONS

- High DC Current Gain and Excellent h_{FE} Linearity
 - : $h_{FE}(1) = 140\sim600$ ($V_{CE} = 1V, I_C = 0.5A$)
 - : $h_{FE}(2) = 70$ (Min.), 200 (Typ.) ($V_{CE} = 1V, I_C = 2A$)
- Low Saturation Voltage
 - : $V_{CE(sat)} = 0.5V$ (Max.) ($I_C = 2A, I_B = 50mA$)

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CBO}	30	V
Collector-Emitter Voltage		V_{CES}	30	V
		V_{CEO}	10	
Emitter-Base Voltage		V_{EBO}	6	V
Collector Current	DC	I_C	2	A
	Pulsed (Note 1)	I_{CP}	5	
Base Current		I_B	0.2	A
Collector Power Dissipation		P_C	750	mW
Junction Temperature		T_j	150	°C
Storage Temperature Range		T_{stg}	-55~150	°C



Weight : 0.21 g

(Note 1) : Pulse Width = 10 ms (Max.), Duty Cycle = 30% (Max.)

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 30\text{ V}, I_E = 0$	—	—	0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = 6\text{ V}, I_C = 0$	—	—	0.1	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10\text{ mA}, I_B = 0$	10	—	—	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 1\text{ mA}, I_C = 0$	6	—	—	V
DC Current Gain	$h_{FE(1)}$ (Note 2)	$V_{CE} = 1\text{ V}, I_C = 0.5\text{ A}$	140	—	600	
	$h_{FE(2)}$	$V_{CE} = 1\text{ V}, I_C = 2\text{ A}$	70	200	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 2\text{ A}, I_B = 50\text{ mA}$	—	0.2	0.5	V
Base-Emitter Voltage	V_{BE}	$V_{CE} = 1\text{ V}, I_C = 2\text{ A}$	—	0.86	1.5	V
Transition Frequency	f_T	$V_{CE} = 1\text{ V}, I_C = 0.5\text{ A}$	—	150	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	27	—	pF

(Note 2) : $h_{FE(1)}$ Classification L : 140~240, M : 200~330, N : 300~450, P : 420~600

